

## isc Silicon PNP Power Transistor

# 2SB1144

#### **DESCRIPTION**

- · · Low Collector Saturation Voltage
  - :  $V_{CE(sat)} = -0.3V(Max)@I_C = -0.5A$
- · Wide Area of Safe Operation
- Complement to Type 2SD1684
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



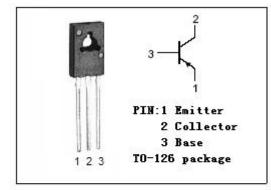
## **APPLICATIONS**

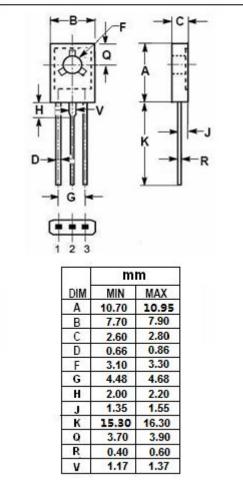
Designed for 100V/1.5A Switching Applications



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-120	٧	
V <sub>CEO</sub>	Collector-Emitter Voltage	-100	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V	
lc	Collector Current-Continuous	-1.5	Α	
I <sub>CP</sub>	Collector Current-Pulse	-2	Α	
P <sub>C</sub>	Collector Power Dissipation @ $T_c$ =25 $^{\circ}$ C	10	W	
	Collector Power Dissipation @ T <sub>a</sub> =25 ℃	1.5		
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	${\mathbb C}$	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA ; I <sub>B</sub> = 0	-100			V		
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -10uA; I <sub>E</sub> = 0	-120			V		
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -10 μ A; I <sub>C</sub> = 0	-6			V		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -500mA; I <sub>B</sub> = -50mA			-0.3	V		
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -500mA; I <sub>B</sub> = -50mA			-1.2	V		
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -100V; I <sub>E</sub> = 0			-0.1	μ <b>A</b>		
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -4V; I <sub>C</sub> = 0			-0.1	μ <b>A</b>		
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -0.1A; V <sub>CE</sub> = -5V	100		400			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	30					

## ♦ h<sub>FE</sub> -1Classifications

Q	s	T
100-200	140-280	200-400

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